

RJK1001DPN-E0

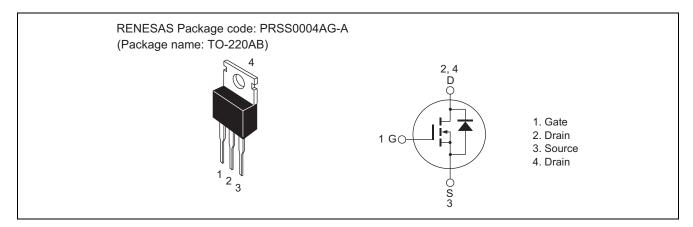
N-Channel MOS FET 100 V, 80 A, 5.5 m Ω

R07DS0619EJ0200 Rev.2.00 Aug 24, 2012

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 4.4 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)
- Package TO-220AB

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	100	V	
Gate to source voltage	V _{GSS}	±20	V	
Drain current	I _D	80	А	
Drain peak current	I _{D (pulse)} Note1	240	А	
Body-drain diode reverse drain current	I _{DR}	80	А	
Avalanche current	I _{AP} Note2	40	А	
Avalanche energy	E _{AS} Note2	160	mJ	
Channel dissipation	Pch Note3	200	W	
Channel to case thermal impedance	θch-c	0.63	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at L = 100 μ H, Tch = 25°C, Rg \geq 50 Ω ,
- 3. Tc = 25°C

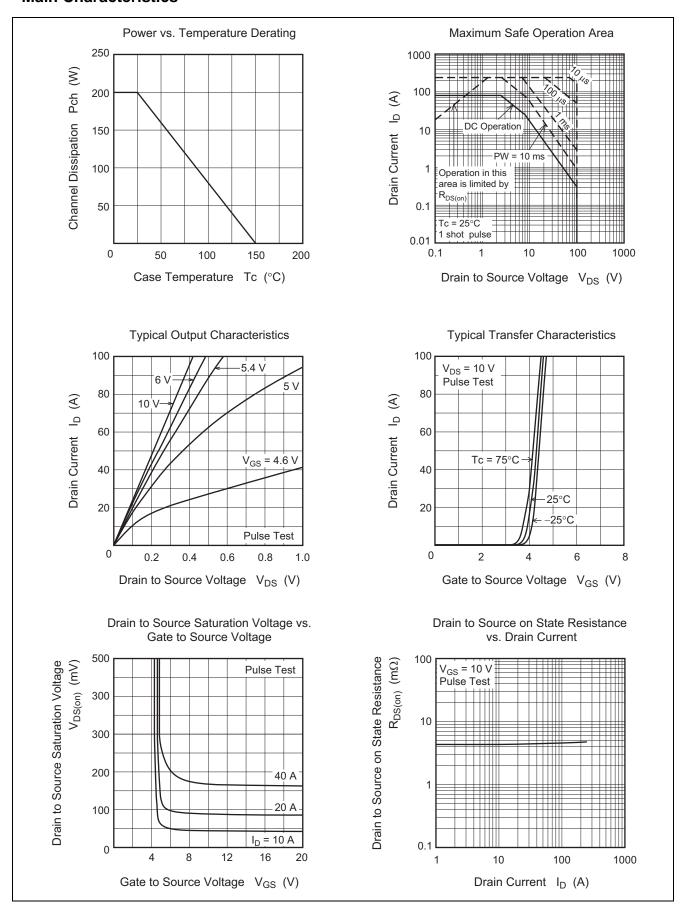
Electrical Characteristics

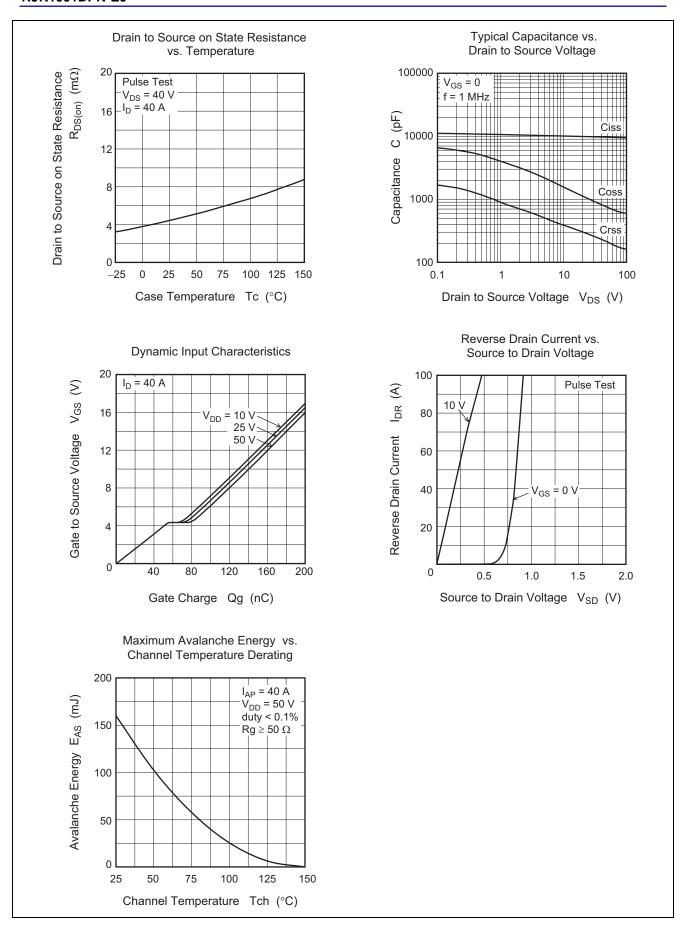
 $(Ta = 25^{\circ}C)$

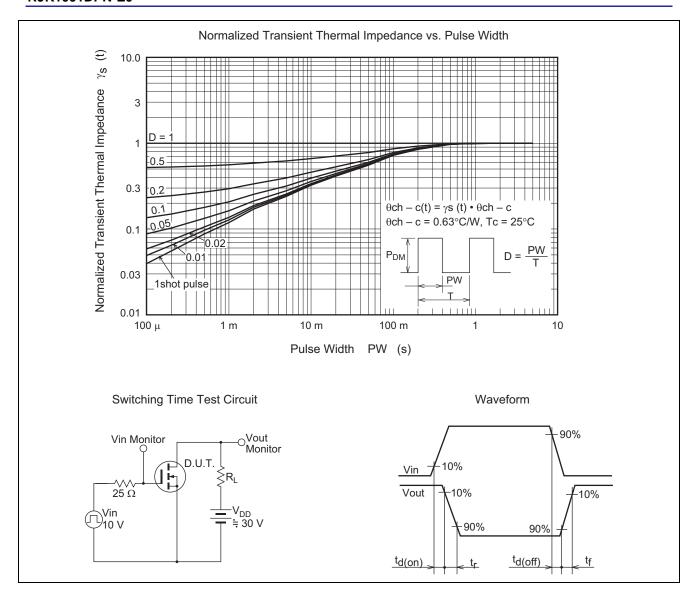
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	_	_	V	$I_D = 10 \text{mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	4.4	5.5	mΩ	$I_D = 40 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Forward transfer admittance	y _{fs}	_	170	_	S	$I_D = 40 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		10000		pF	V _{DS} = 10 V
Output capacitance	Coss	_	1500	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	370	_	pF	f = 1 MHz
Gate Resistance	Rg	_	1.6	_	Ω	
Total gate charge	Qg	_	147	_	nC	V _{DD} = 50 V
Gate to source charge	Qgs	_	50	_	nC	V _{GS} = 10 V, I _D = 40 A
Gate to drain charge	Qgd	_	30	_	nC	
Turn-on delay time	t _{d(on)}	_	53	_	ns	V _{GS} = 10 V
Rise time	t _r	_	20	_	ns	$\begin{split} I_D &= 40 \text{ A} \\ V_{DD} &\cong 30 \text{ V} \\ Rg &= 4.7 \Omega \end{split}$
Turn-off delay time	t _{d(off)}	_	110	_	ns	
Fall time	t _f	_	22	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.85	1.5	V	$I_F = 80 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	75	_	ns	$I_F = 80 \text{ A}, V_{GS} = 0$
						di _F /dt = 100 A/μs

Notes: 4. Pulse test

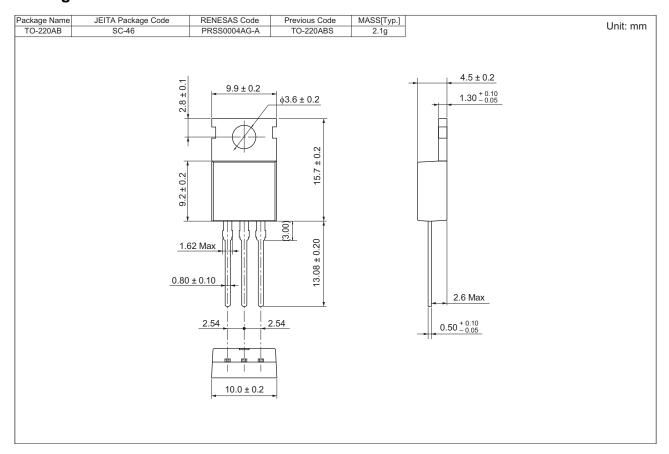
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK1001DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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